

SOT23 NPN SILICON PLANAR SMALL SIGNAL TRANSISTOR

FMMT2484

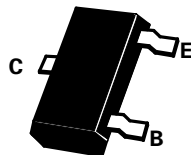
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FEATURES

* 60 Volt V_{CE0}

PARTMARKING DETAIL – 4G



SOT23

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	6	V
Peak Pulse Current	I_{CM}	200	mA
Continuous Collector Current	I_C	50	mA
Power Dissipation at $T_{amb}=25^\circ\text{C}$	P_{tot}	330	mW
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60		V	$I_C=10\mu\text{A}, I_E=0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	60		V	$I_C=10\text{mA}, I_B=0^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6		V	$I_E=10\mu\text{A}, I_C=0$
Collector Cut-Off Current	I_{CBO}		10 10	nA μA	$V_{CB}=45\text{V}, I_E=0$ $V_{CB}=45\text{V}, I_E=0, T_{amb}=150^\circ\text{C}$
Emitter Cut-Off Current	I_{EBO}		10	nA	$V_{BE}=5\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.35	V	$I_C=1\text{mA}, I_B=100\mu\text{A}^*$
Base-Emitter Voltage	V_{BE}		0.95	V	$I_C=1\text{mA}, V_{CE}=5\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	30 100 20 175 200 250	500 800		$I_C=1\mu\text{A}, V_{CE}=5\text{V}^*$ $I_C=10\mu\text{A}, V_{CE}=5\text{V}^*$ $I_C=10\mu\text{A}, V_{CE}=5\text{V}, T_{amb}=55^\circ\text{C}$ $I_C=100\mu\text{A}, V_{CE}=5\text{V}^*$ $I_C=500\mu\text{A}, V_{CE}=5\text{V}^*$ $I_C=1\text{mA}, V_{CE}=5\text{V}^*$ $I_C=10\text{mA}, V_{CE}=5\text{V}^*$
Output Capacitance	C_{obo}		6	pF	$V_{CB}=5\text{V}, I_E=0, f=140\text{kHz}$
Input Capacitance	C_{ibo}		6	pF	$V_{BE}=0.5\text{V}, I_E=0, f=140\text{kHz}$
Noise Figure	N		3	dB	$I_C=200\mu\text{A}, V_{CE}=5\text{V}, R_g=2\text{k}\Omega$ $f=1\text{kHz}, f=200\text{Hz}$
			3	dB	$I_C=200\mu\text{A}, V_{CE}=5\text{V}, R_g=2\text{k}\Omega$ $f=30\text{Hz to } 15\text{kHz at } -3\text{dB points}$

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$